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LMH6601 and LMH6601-Q1 250-MHz, 2.4-V CMOS Operational Amplifier With Shutdown

Technical [Documents](#page-32-0)

- -
	-
- V⁻, Unless Specified
-
-
-
-
- Phase shutdown feature.
- Rail-to-Rail Output
- 2.4-V to 5.5-V Single-Supply Operating Range
- 6-Pin SC70 Package

LMH6601-Q1 **2 Applications**

-
- **Charge Amplifiers**
-
- Sample and Holds
- Transimpedance Amplifiers
- **Line Drivers**
- High-Impedance Buffers
- Automotive

1 Features 3 Description

Tools & **[Software](#page-32-0)**

1.0 LMH6601-Q1 Qualified for Automotive The LMH6601 device is a low-voltage (2.4 V to 5.5
V), high-speed voltage feedback operational amplifier V), high-speed voltage feedback operational amplifier
Suitable for use in a variety of consumer and
ADC-Q100 Grade 3 industrial applications With a bandwidth of 125 MHz AEC-Q100 Grade 3 industrial applications. With a bandwidth of 125 MHz
40°C to 85°C Ambient Operating a same a gain of +2 and ensured high-output current of at a gain of $+2$ and ensured high-output current of Temperature Range
 -3.3% T -2.8% A -3.1% P -150 O to line driver applications, including HDTV. Low-input $V_S = 3.3$ V, T_A = 25°C, A_V = 2 V/V, R_L = 150 Ω to bias current (50 pA maximum), rail-to-rail output, and bias current (50 pA maximum), rail-to-rail output, and low current noise allow the use of the LMH6601 in • 125 MHz −3 dB Small Signal Bandwidth various industrial applications such as • 75 MHz −3 dB Large Signal Bandwidth transimpedance amplifiers, active filters, or highimpedance buffers. The LMH6601 is an attractive • 30 MHz Large Signal 0.1-dB Gain Flatness solution for systems which require high performance • 260 V/μs Slew Rate
260 V/μs Slew Rate at low supply voltages. The LMH6601 is available in a
25%/0.25° Differential Gain and Differential 6. B. C.70 package and includes a micropower 6-pin SC70 package, and includes a micropower

Support & **[Community](#page-32-0)**

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Device Information[\(1\)](#page-0-0)

(1) For all available packages, see the orderable addendum at Video Amplifiers view of the end of the data sheet.

Response at ^a Gain of +2 • Set-Top Boxes **for Various Supply Voltages**

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (March 2013) to Revision F Page

Changes from Revision D (March 2013) to Revision E Page

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5 Pin Configuration and Functions

Pin Functions

6 Specifications

6.1 Absolute Maximum Ratings(1)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Negative input current implies current flowing out of the device.

(3) The maximum continuous output current (I_{OUT}) is determined by device power dissipation limitations.

6.2 ESD Ratings - for LMH6601

(1) Human Body Model, applicable std. MIL-STD-883, Method 3015.7.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

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6.3 ESD Ratings - for LMH6601-Q1

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.4 Recommended Operating Conditions(1)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.5 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](http://www.ti.com/lit/pdf/spra953).

6.6 Electrical Characteristics, 5 V

Single-Supply with V_S= 5 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V⁻ unless otherwise specified.⁽¹⁾

(1) *Electrical [Characteristics,](#page-3-3) 5 V* values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

Electrical Characteristics, 5 V (continued)

Single-Supply with V_S= 5 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.^{[\(1\)](#page-5-1)}

(3) Drift determined by dividing the change in parameter at temperature extremes by the total temperature change.
(4) This parameter is ensured by design and/or characterization and is not tested in production.

This parameter is ensured by design and/or characterization and is not tested in production.

 (5) \overline{SD} logic is CMOS compatible. To ensure proper logic level and to minimize power supply current, \overline{SD} should typically be less than 10% of total supply voltage away from either supply rail.

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Electrical Characteristics, 5 V (continued)

(6) " V_{ID} " is input differential voltage (input overdrive).

6.7 Electrical Characteristics, 3.3 V

Single-Supply with V_S= 3.3 V, A_V = +2, R_F = 604Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.⁽¹⁾

(1) *Electrical [Characteristics,](#page-5-0) 3.3 V* values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that ${\sf T_J}$ = ${\sf T_A}.$ No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

Electrical Characteristics, 3.3 V (continued)

Single-Supply with V_S= 3.3 V, A_V = +2, R_F = 604Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.^{[\(1\)](#page-7-2)}

(3) Drift determined by dividing the change in parameter at temperature extremes by the total temperature change.

(4) This parameter is ensured by design and/or characterization and is not tested in production.

 (5) \overline{SD} logic is CMOS compatible. To ensure proper logic level and to minimize power supply current, \overline{SD} should typically be less than 10% of total supply voltage away from either supply rail.

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Electrical Characteristics, 3.3 V (continued)

(6) " V_{ID} " is input differential voltage (input overdrive).

6.8 Electrical Characteristics, 2.7 V

Single-Supply with V_S = 2.7 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.⁽¹⁾

(1) *Electrical [Characteristics,](#page-7-0) 2.7 V* values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not ensured on shipped production material.

Electrical Characteristics, 2.7 V (continued)

Single-Supply with V_S = 2.7 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.^{[\(1\)](#page-9-1)}

(3) Drift determined by dividing the change in parameter at temperature extremes by the total temperature change.
(4) This parameter is ensured by design and/or characterization and is not tested in production.

 $\frac{1}{4}$ This parameter is ensured by design and/or characterization and is not tested in production.
(5) \overline{SD} logic is CMOS compatible. To ensure proper logic level and to minimize power supply cu (5) SD logic is CMOS compatible. To ensure proper logic level and to minimize power supply current, SD should typically be less than 10% of total supply voltage away from either supply rail.

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Electrical Characteristics, 2.7 V (continued)

Single-Supply with V_S = 2.7 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.^{[\(1\)](#page-9-1)}

(6) " V_{ID} " is input differential voltage (input overdrive).

6.9 Switching Characteristics, 5 V

Single-Supply with VS= 5 V, AV = +2, RF = 604 Ω, SD tied to V+, VOUT = VS/2, RL = 150 Ω to V− unless otherwise specified.

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6.10 Switching Characteristics, 3.3 V

(1) *Electrical [Characteristics,](#page-5-0) 3.3 V* values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T_J = T_A . No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where T_J > T_A .

6.11 Switching Characteristics, 2.7 V

Single-Supply with V_s = 2.7 V, A_V = +2, R_F = 604 Ω, \overline{SD} tied to V⁺, V_{OUT} = V_S/2, R_L = 150 Ω to V[−] unless otherwise specified.⁽¹⁾

(1) *Electrical [Characteristics,](#page-7-0) 2.7 V* values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

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6.12 Typical Characteristics

Unless otherwise noted, all data is with A_ν = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, SD tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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Typical Characteristics (continued)

Unless otherwise noted, all data is with A_V = +2, R_F = R_G = 604 Ω, V_S = 3.3V, V_{OUT} = V_S/2, \overline{SD} tied to V⁺, R_L = 150 Ω to V⁻, T $= 25^{\circ}$ C.

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7 Detailed Description

7.1 Overview

The high-speed, ultra-high input impedance of the LMH6601 and its fast slew rate make the device an ideal choice for video amplifier and buffering applications. There are cost benefits in having a single operating supply. Single-supply video systems can take advantage of the low supply voltage operation of the LMH6601 along with its ability to operate with input common-mode voltages at or slightly below the V⁻ rail. Additional cost savings can be achieved by eliminating or reducing the value of the input and output AC-coupling capacitors commonly employed in single-supply video applications.

7.2 Feature Description

7.2.1 Shutdown Capability and Turn On/Off Behavior

With the device in shutdown mode, the output goes into high-impedance ($R_{\text{OUT}} > 100 \text{ M}\Omega$) mode. In this mode, the only path between the inputs and the output pin is through the external components around the device. So, for applications where there is active signal connection to the inverting input, with the LMH6601 in shutdown, the output could show signal swings due to current flow through these external components. For noninverting amplifiers in shutdown, no output swings would occur, because of complete input-output isolation, with the exception of capacitive coupling.

For maximum power saving, the LMH6601 supply current drops to around 0.1 μA in shutdown. All significant power consumption within the device is disabled for this purpose. Because of this, the LMH6601 turnon time is measured in microseconds whereas its turnoff is fast (nanoseconds) as would be expected from a high speed device like this.

The LMH6601 \overline{SD} pin is a CMOS compatible input with a pico-ampere range input current drive requirement. This pin must be tied to a level or otherwise the device state would be indeterminate. The device shutdown threshold is half way between the V⁺ and V[−] pin potentials at any supply voltage. For example, with V⁺ tied to 10 V and V⁻ equal to 5 V, you can expect the threshold to be at 7.5 V. The state of the device (shutdown or normal operation) is ensured over temperature as long as the \overline{SD} pin is held to within 10% of the total supply voltage.

For V^+ = 10 V, V^- = 5 V, as an example:

- Shutdown Range 5 V ≤ \overline{SD} ≤ 5.5 V
- Normal Operation Range $9.5 \text{ V} \leq \overline{\text{SD}} \leq 10 \text{ V}$

7.2.2 Overload Recovery and Swing Close to Rails

The LMH6601 can recover from an output overload in less than 20 ns. See [Figure](#page-19-3) 47 for the input and output scope photos:

Figure 47. LMH6601 Output Overload Recovery Waveform

In [Figure](#page-19-3) 47, the input step function is set so that the output is driven to one rail and then the other and then the output recovery is measured from the time the input crosses 0 V to when the output reaches this point.

Feature Description (continued)

Also, when the LMH6601 input voltage range is exceeded near the V⁺ rail, the output does not experience output phase reversal, as do some op amps. This is particularly advantageous in applications where output phase reversal must be avoided at all costs, such as in servo loop control among others. This adds to the set of features of the LMH6601, which make this device easy to use.

In addition, the LMH6601 output swing close to either rail is well-behaved as shown in the scope photo of [Figure](#page-20-1) 48.

Figure 48. *Clean* **Swing of the LMH6601 to Either Rail**

With some op amps, when the output approaches either one or both rails and saturation starts to set in, there is significant increase in the transistor parasitic capacitances which leads to loss of Phase Margin. That is why with these devices, there are sometimes hints of instability with output close to the rails. With the LMH6601, as can be seen in [Figure](#page-20-1) 48, the output waveform remains free of instability throughout its range of voltages.

7.3 Device Functional Modes

7.3.1 Optimizing Performance

With many op amps, additional device nonlinearity and sometimes less loop stability arises when the output must switch from current-source mode to current-sink mode or vice versa. When it comes to achieving the lowest distortion and the best Differential Gain/ Differential Phase (DG/ DP, broadcast video specs), the LMH6601 is optimized for single-supply DC-coupled output applications where the load current is returned to the negative rail (V[−]). That is where the output stage is most linear (lowest distortion) and which corresponds to unipolar current flowing out of this device. To that effect, it is easy to see that the distortion specifications improve when the output is only sourcing current which is the distortion-optimized mode of operation for the LMH6601. In an application where the LMH6601 output is AC-coupled or when it is powered by separate dual supplies for V ⁺ and V − , the output stage supplies both source and sink current to the load and results in less than optimum distortion (and DG/DP). [Figure](#page-21-0) 49 compares the distortion results between a DC- and an AC-coupled load to show the magnitude of this difference. See the DG/DP plots, [Figure](#page-17-0) 43 through [Figure](#page-17-0) 46, in *Typical [Characteristics](#page-11-0)*, for a comparison between DC- and AC-coupling of the video load.

Device Functional Modes (continued)

Figure 49. Distortion Comparison between DC- and AC-Coupling of the Load

In certain applications, it may be possible to optimize the LMH6601 for best distortion (and DG/DP) even though the load may require bipolar output current by adding a pulldown resistor to the output. Adding an output pulldown resistance of appropriate value could change the LMH6601 output loading into source-only. This comes at the price of higher total power dissipation and increased output current requirement.

[Figure](#page-21-1) 50 shows how to calculate the pulldown resistor value for both the dual-supply and for the AC-coupled load applications.

Furthermore, with a combination of low closed-loop gain setting (that is, $A_V = +1$ for example where device bandwidth is the highest), light output loading (R_L > 1 kΩ), and with a significant capacitive load (C_L > 10 pF), the LMH6601 is most stable if output sink current is kept to less than about 5 mA. The pulldown method described in [Figure](#page-21-1) 50 is applicable in these cases as well where the current that would normally be sunk by the op amp is diverted to the R_P path instead.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 DC-Coupled, Single-Supply Baseband Video Amplifier and Driver

The LMH6601 output can swing very close to either rail to maximize the output dynamic range which is of particular interest when operating in a low-voltage, single-supply environment. Under light output load conditions, the output can swing as close as a few mV of either rail. This also allows a video amplifier to preserve the video black level for excellent video integrity. In the example shown in [Figure](#page-22-2) 51, the baseband video output is amplified and buffered by the LMH6601 which then drives the 75-Ω back-terminated video cable for an overall gain of +1 delivered to the 75-Ω load. The input video would normally have a level between 0 V to approximately 0.75 V.

Figure 51. Single-Supply Video Driver Capable of Maintaining Accurate Video Black Level

With the LMH6601 input common-mode range including the V⁻ (ground) rail, there will be no need for ACcoupling or level shifting and the input can directly drive the noninverting input which has the additional advantage of high amplifier input impedance. With LMH6601's wide rail-to-rail output swing, as stated earlier, the video black level of 0 V is maintained at the load with minimal circuit complexity and using no AC-coupling capacitors. Without true rail-to-rail output swing of the LMH6601, and more importantly without the LMH6601's ability of exceedingly close swing to V[−], the circuit would not operate properly as shown at the expense of more complexity. This circuit will also work for higher input voltages. The only significant requirement is that there is at least 1.8 V from the maximum input voltage to the positive supply (V^+) .

The Composite Video Output of some low-cost consumer video equipment consists of a current source which develops the video waveform across a load resistor (usually 75 Ω), as shown in [Figure](#page-23-0) 52. With these applications, the same circuit configuration just described and shown in [Figure](#page-23-0) 52 will be able to buffer and drive the Composite Video waveform which includes sync and video combined. However, with this arrangement, the LMH6601 supply voltage must be at least 3.3 V or higher to allow proper input common-mode voltage headroom because the input can be as high as 1-V peak.

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Application Information (continued)

Figure 52. Single-Supply Composite Video Driver for Consumer Video Outputs

If the Video In signal is Composite Video with negative going Sync tip, a variation of the previous configurations should be used. This circuit produces a unipolar (more than 0 V) DC-coupled single-supply video signal as shown in [Figure](#page-23-1) 53.

Figure 53. Single-Supply, DC-Coupled Composite Video Driver for Negative Going Sync Tip

In the circuit of [Figure](#page-23-1) 53, the input is shifted positive by means of R_1 , R_2 , and R_T in order to satisfy the commonmode input range of the U1. The signal will loose 20% of its amplitude in the process. The closed-loop gain of U1 must be set to make up for this 20% loss in amplitude. This gives rise to the gain expression shown in [Equation](#page-23-2) 1, which is based on a getting a 2 V_{PP} output with a 0.8 V_{PP} input:

$$
\frac{RF}{R_G||R_3} = \frac{2V}{0.8V} - 1 = 1.5V/V
$$
\n(1)

 R_3 will produce a negative shift at the output due to V_S (3.3 V in this case). R_3 must be set so that the Video In sync tip (-0.3 V at R_T or 0.61 V at U1 noninverting input) corresponds to near 0 V at the output.

 R_{F} $\frac{R_F}{R_3} = \frac{0.61}{3.3V - 0.61} \left| 1 + \frac{R_F}{R_G} \right| = 0.227$ \vert ' T R_{G} l, \setminus $\left(\begin{array}{c} R_E \end{array}\right)$ ¨ © § $1 + \frac{R_F}{R_G}$ l, \setminus $\left(\begin{matrix} R_E \end{matrix}\right)$ \parallel © R_G

(2)

[Equation](#page-23-3) 1 and Equation 2 must be solved simultaneously to arrive at the values of R_3 , R_F , and R_G which will satisfy both. From the data sheet, one can set $R_F = 620 \Omega$ to be close to the recommended value for a gain of +2. It is easier to solve for R_G and R₃ by starting with a good estimate for one and iteratively solving [Equation](#page-23-2) 1 and [Equation](#page-23-3) 2 to arrive at the results. Here is one possible iteration cycle for reference:

 $R_F = 620 \Omega$ (3)

Application Information (continued)

ESTIMATE $R_G(\Omega)$	CALCULATED (from Equation 2) $R3(\Omega)$	Equation 1 LHS CALCULATED	COMMENT (COMPARE Equation 1 LHS calculated to RHS)		
1k	1.69k	0.988	Increase Equation 1 LHS by reducing R_G		
820	1.56k	1.15	Increase Equation 1 LHS by reducing R_G		
620	1.37k	1.45	Increase Equation 1 LHS by reducing R _G		
390	239	4.18	Reduce Equation 1 LHS by increasing R_G		
560	1.30k	1.59	Close to target value of 1.5V/V for Equation 1		

Table 1. Finding External Resistor Values by Iteration for [Figure](#page-23-1) 53

The final set of values for R_G and R₃ in [Table](#page-24-1) 1 are values which will result in the proper gain and correct video levels (0 V to 1 V) at the output (V_{LOAD}) .

8.1.2 How to Pick the Right Video Amplifier

Apart from output current drive and voltage swing, the op amp used for a video amplifier and cable driver should also possess the minimum requirement for speed and slew rate. For video type loads, it is best to consider Large Signal Bandwidth (or LSBW in the TI data sheet tables) as video signals could be as large as 2 V_{PP} when applied to the commonly used gain of +2 configuration. Because of this relatively large swing, the op amp Slew Rate (SR) limitation should also be considered. [Table](#page-24-2) 2 shows these requirements for various video line rates calculated using a rudimentary technique and intended as a first-order estimate only.

Table 2. Rise Time, −3 dB BW, and Slew Rate Requirements for Various Video Line Rates

VIDEO STANDARD	LINE RATE (HxV)	REFRESH RATE (Hz)	HORIZONTA ACTIVE (KH%)	VERTICAL ACTIVE (KV%)	PIXEL TIME (ns)	RISE TIME (ns)	LSBW (MHz)	SR $(V/\mu s)$
TV NTSC	451x483	30	84	92	118.3	39.4	9	41
VGA	640x480	75	80	95	33	11	32	146
SVGA	800x600	75	76	96	20.3	6.8	52	237
XGA	1024x768	75	77	95	12.4	4.1	85	387
SXGA	1280x1024	75	75	96	7.3	2.4	143	655
UXGA	1600x1200	75	74	96	4.9	1.6	213	973

For any video line rate (HxV corresponding to the number of Active horizontal and vertical lines), the speed requirements can be estimated if the Horizontal Active (KH%) and Vertical Active (KV%) numbers are known. These percentages correspond to the percentages of the active number of lines (horizontal or vertical) to the total number of lines as set by VESA standards. Here are the general expressions and the specific calculations for the SVGA line rate shown in [Table](#page-24-2) 2.

$$
PIXEL_TIME (ns) = \frac{\frac{1}{REFREESH_RATE} \times KH \times KV}{H \times V} \times 1 \times 10^5
$$

$$
= \frac{\frac{1}{75 Hz} \times 76 \times 96}{800 \times 600} \times 1 \times 10^5 = 20.3 ns
$$
(4)

Requiring that an "On" pixel is illuminated to at least 90 percent of its final value before changing state will result in the rise/fall time equal to, at most, ⅓ the pixel time as shown in [Equation](#page-24-3) 5:

RISE/FALL_TIME =
$$
\frac{\text{PIXEL_TIME}}{3} = \frac{20.3 \text{ ns}}{3} = 6.8 \text{ ns}
$$

Assuming a single pole frequency response roll-off characteristic for the closed-loop amplifier used, we have:

RISE/FALL_TIME =
$$
\frac{1}{3} = \frac{3}{3} = 6.8 \text{ ns}
$$

ing a single pole frequency response roll-off of
-3 dB_BW =
$$
\frac{0.35}{RISE/FALL_TIME} = \frac{0.35}{6.8 \text{ ns}} = 52 \text{ MHz}
$$

(5)

(6)

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Rise/Fall times are 10%-90% transition times, which for a 2 V_{PP} video step would correspond to a total voltage shift of 1.6V (80% of 2 V). So, the Slew Rate requirement can be calculated as follows:

$$
SR(V/\mu s) = \frac{1.6V}{RISE/FALL_TIME (ns)} \times 1 \times 10^3 = \frac{1.6V}{6.8 \text{ ns}} = 237(V/\mu s)
$$
\n(7)

The LMH6601 specifications show that it would be a suitable choice for video amplifiers up to and including the SVGA line rate as demonstrated above.

For more information about this topic and others relating to video amplifiers, see Application Note 1013, *Video Amplifier Design for Computer Monitors* [\(SNVA031](http://www.ti.com/lit/pdf/SNVA031)).

8.1.3 Current to Voltage Conversion (Transimpedance Amplifier (TIA)

Being capable of high speed and having ultra low input bias current makes the LMH6601 a natural choice for Current to Voltage applications such as photodiode I-V conversion. In these type of applications, as shown in [Figure](#page-25-0) 54, the photodiode is tied to the inverting input of the amplifier with R_F set to the proper gain (gain is measured in $Ω$).

 C_{F} R_E - **LMH6601** D_1 Ō **VOUT U1** C_D ∷ C_A VBIAS

Figure 54. Typical Connection of a Photodiode Detector to an Op Amp

With the LMH6601 input bias current in the femto-amperes range, even large values of gain (R_F) do not increase the output error term appreciably. This allows circuit operation to a lower light intensity level which is always of special importance in these applications. Most photo-diodes have a relatively large capacitance (C_D) which would be even larger for a photo-diode designed for higher sensitivity to light because of its larger area. Some applications may run the photodiode with a reverse bias to reduce its capacitance with the disadvantage of increased contributions from both dark current and noise current. [Figure](#page-25-1) 55 shows a typical photodiode capacitance plot vs. reverse bias for reference.

Figure 55. Typical Capacitance vs. Reverse Bias (Source: OSI Optoelectronics)

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The diode capacitance (C_D) combined with the input capacitance of the LMH6601 (C_A) has a bearing on the stability of this circuit and how it is compensated. With large transimpedance gain values (R_F) , the total combined capacitance on the amplifier inverting input (C_{IN} = C_D + C_A) will work against R_F to create a zero in the Noise Gain (NG) function (see [Figure](#page-26-0) 56). If left untreated, at higher frequencies where NG equals the open-loop transfer function excess phase shift around the loop (approaching 180°) and therefore, the circuit could be unstable. This is illustrated in [Figure](#page-26-0) 56.

Figure 56. Transimpedance Amplifier Graphical Stability Analysis and Compensation

[Figure](#page-26-0) 56 shows that placing a capacitor, C_F , with the proper value, across R_F will create a pole in the NG function at f_p. For optimum performance, this capacitor is usually picked so that NG is equal to the open-loop gain of the op amp at fp. This will cause a "flattening" of the NG slope beyond the point of intercept of the two plots (open-loop gain and NG) and will results in a Phase Margin (PM) of 45° assuming f_P and f_Z are at least a decade apart. This is because at the point of intercept, the NG pole at f_P will have a 45° phase lead contribution which leaves 45° of PM. For reference, [Figure](#page-26-0) 56 also shows the transimpedance gain (I-V $(Ω)$)

Here is the theoretical expression for the optimum C_F value and the expected -3 -dB bandwidth:

$$
C_F = \sqrt{\frac{C_{IN}}{2\pi (GBWP)R_F}}
$$
\n
$$
f_{-3 dB} \approx \sqrt{\frac{GBWP}{2\pi R_F C_{IN}}}
$$
\n(8)

[Table](#page-26-1) 3 lists the results, along with the assumptions and conditions, of testing the LMH6601 with various photodiodes having different capacitances (C_D) at a transimpedance gain (R_F) of 10 kΩ.

C_D (pF)	C_{IN} (pF)	C _F _CALCULATED (pF)	C_F USED (pF)	-3 dB BW CALCULATED (MHz)	-3 dB BW MEASURED (MHz)	STEP RESPONSE OVERSHOOT (%)
10	12	1.1		14	15	
50	52	2.3				
500	502	7.2			2.5	

Table 3. Transimpedance Amplifier Compensation and Performance Results for [Figure](#page-25-0) 54

 $C_A = 2$ pF GBWP = 155 MHz $V_S = 5$ V (10)

8.1.4 Transimpedance Amplifier Noise Considerations

When analyzing the noise at the output of the I-V converter, it is important to note that the various noise sources (that is, op amp noise voltage, feedback resistor thermal noise, input noise current, photodiode noise current) do not all operate over the same frequency band. Therefore, when the noise at the output is calculated, this should be taken into account.

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The op amp noise voltage will be gained up in the region between the noise gain's "zero" and its "pole" (f_z and f_o in [Figure](#page-26-0) 56). The higher the values of R_F and C_{IN} , the sooner the noise gain peaking starts and therefore its contribution to the total output noise would be larger. It is obvious to note that it is advantageous to minimize C_{IN} (for example, by proper choice of op amp, by applying a reverse bias across the diode at the expense of excess dark current and noise). However, most low noise op amps have a higher input capacitance compared to ordinary op amps. This is due to the low noise op amp's larger input stage.

8.1.5 Charge Preamplifier

 c_{F} $R_F = 10 M\Omega$ to 10 G Ω $R_S = 1$ M Ω or SMALLER FOR HIGH COUNTING RATES $C_F = 1 pF$ $C_D = 1$ pF to 10 μ F $V_{\text{OUT}} = Q/C_F$ WHERE Q is CHARGE CREATED BY ONE PHOTON or PARTICLE **ADJUST V_{BIAS} FOR MAXIMUM SNR**

Figure 57. Charge Preamplifier Taking Advantage of the Femto-Ampere Range Input Bias Current of the LMH6601

8.1.6 Capacitive Load

The LMH6601 can drive a capacitive load of up to 1000 pF with correct isolation and compensation. [Figure](#page-27-1) 58 illustrates the in-loop compensation technique to drive a large capacitive load.

Figure 58. In-Loop Compensation Circuit for Driving a Heavy Capacitive Load

When driving a high-capacitive load, an isolation resistor (R_S) should be connected in series between the op amp output and the capacitive load to provide isolation and to avoid oscillations. A small-value capacitor (C_F) is inserted between the op amp output and the inverting input as shown such that this capacitor becomes the dominant feedback path at higher frequency. Together these components allow heavy capacitive loading while keeping the loop stable.

There are few factors which affect the driving capability of the op amp:

- Op amp internal architecture
- Closed-loop gain and output capacitor loading

[Table](#page-28-1) 4 shows the measured step response for various values of load capacitors (C_L), series resistor (R_S) and feedback resistor (C_F) with gain of +2 (R_F = R_G = 604 Ω) and R_L = 2 kΩ:

Table 4. LMH6601 Step Response Summary for the Circuit of [Figure](#page-27-1) 58

(1) Response limited by input step generator rise time of 5 ns

[Figure](#page-28-2) 59 shows the increase in rise/fall time (bandwidth decrease) at V_{OUT} with larger capacitive loads, illustrating the trade-off between the two:

Figure 59. LMH6601 In-Loop Compensation Response

8.2 Typical Application

8.2.1 SAG Compensation for AC-Coupled Video

Many monitors and displays accept AC-coupled inputs. This simplifies the amplification and buffering task in some respects. The capacitors shown in [Figure](#page-28-3) 60 (except C_{G2}), and especially C_0 , are the large electrolytic type which are considerably costly and take up valuable real estate on the board. It is possible to reduce the value of the output coupling capacitor, C_0 , which is the largest of all, by using what is called SAG compensation. SAG refers to what the output video experiences due to the low frequency video content it contains which cannot adequately go through the output AC-coupling scheme due to the low frequency limit of this circuit. The −3 dB low frequency limit of the output circuit is given by:

f_low_frequency (−3 dB)= 1/ (2*π* 75*2(Ω) * Co) = ∼ 4.82 Hz for CO = 220 μF (11)

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Typical Application (continued)

8.2.2 Design Requirements

As shown in [Figure](#page-28-3) 60, R_1 and R_2 simply set the input to the center of the input linear range while C_{IN} AC couples the video onto the input of the op amp. The op amp is set for a closed-loop gain of 2 with R_F and R_G . C_G is there to make sure the device output is also biased at mid-supply. Because of the DC bias at the output, the load must be AC-coupled as well through C_0 . Some applications implement a small valued ceramic capacitor (not shown) in parallel with C_O which is electrolytic. The reason for this is that the ceramic capacitor will tend to shunt the inductive behavior of the Electrolytic capacitor at higher frequencies for an improved overall low impedance output.

 C_{G2} is intended to boost the high-frequency gain to improve the video frequency response. This value is to be set and trimmed on the board to meet the specific system requirements of the application.

A possible implementation of the SAG compensation is shown in [Figure](#page-29-0) 61.

Figure 61. AC-Coupled Video Amplifier/Driver With SAG Compensation

8.2.3 Detailed Design Procedure

In the circuit of [Figure](#page-29-0) 61, the output coupling capacitor value and size is reduced at the expense of a slightly more complicated circuitry. Note that C_1 is not only part of the SAG compensation, but it also sets the amplifier's DC gain to 0 dB so that the output is set to mid-rail for linearity purposes. Also, exceptionally high values are chosen for the R₁ and R₂ biasing resistors (510 kΩ). The LMH6601 has extremely low input bias current which allows this selection thereby reducing the C_{IN} value in this circuit such that C_{IN} can even be a nonpolar capacitor which will reduce cost.

At high enough frequencies where both CO and C1 can be considered to be shorted out, R_3 shunts R_4 and the closed-loop gain is determined by:

Closed_loop_Gain (V/V) = VL/VIN = (1+ (R₃||R₄)/ R₅) x [R_L/(R^L+R_O)]= 0.99 V/V (12)

At intermediate frequencies, where the C_O, R_O, R_L path experiences low frequency gain loss, the R₃, R₅, C₁ path provides feedback from the load side of C_0 . With the load side gain reduced at these lower frequencies, the feedback to the op amp inverting node reduces, causing an increase at the output of the op amp as a response.

For NTSC video, low values of C_O influence how much video black level shift occurs during the vertical blanking interval (~1.5 ms) which has no video activity and thus is sensitive to the charge dissipation of the C_O through the load which could cause output SAG. An especially tough pattern is the NTSC pattern called "Pulse & Bar." With this pattern the entire top and bottom portion of the field is black level video where, for about 11 ms, C_0 is discharging through the load with no video activity to replenish that charge.

Typical Application (continued)

8.2.4 Application Curves

∨ertical Sync $(0.2V/Div)$ Svn 'n lote the load signal SAG
-90 mV) with "Pulse & Bai Pattern M α 2 ms/DIV

[Figure](#page-30-0) 62 shows the output of the [Figure](#page-29-0) 61 circuit highlighting the SAG.

Figure 62. AC-Coupled Video Amplifier/Driver Output Scope Photo Showing Video SAG

With the circuit of [Figure](#page-29-0) 61 and any other AC-coupled pulse amplifier, the waveform duty cycle variations exert additional restrictions on voltage swing at any node. This is illustrated in the waveforms shown in [Figure](#page-30-1) 63.

If a stage has a 3 V_{PP} unclipped swing capability available at a given node, as shown in [Figure](#page-30-1) 63, the maximum allowable amplitude for an arbitrary waveform is $\frac{1}{2}$ of 3 V or 1.5 V_{PP}. This is due to the shift in the average value of the waveform as the duty cycle varies. [Figure](#page-30-1) 63 shows what would happen if a 2 V_{PP} signal were applied. A low duty cycle waveform, such as the one in [Figure](#page-30-1) 63*B*, would have high positive excursions. At low enough duty cycles, the waveform could get clipped on the top, as shown, or a more subtle loss of linearity could occur prior to full-blown clipping. The converse of this occurs with high duty cycle waveforms and negative clipping, as depicted in [Figure](#page-30-1) 63*C*.

Figure 63. Headroom Considerations With AC-Coupled Amplifiers

9 Power Supply Recommendations

The LMH6601 can operate off a single-supply or with dual supplies. The input CM capability of the parts (CMVR) extends all the way down to the V- rail to simplify single-supply applications. Supplies should be decoupled with low-inductance, often ceramic, capacitors to ground less than 0.5 inches from the device pins. TI recommends the use of ground plane, and as in most high-speed devices, it is advisable to remove ground plane close to device sensitive pins such as the inputs.

10 Layout

10.1 Layout Guidelines

Generally, a good high-frequency layout will keep power supply and ground traces away from the inverting input and output pins. Parasitic capacitances on these nodes to ground will cause frequency response peaking and possible circuit oscillations (see Application Note OA-15, *Frequent Faux Pas in Applying Wideband Current Feedback Amplifiers*, [SNOA367,](http://www.ti.com/lit/pdf/SNOA367) for more information).

10.2 Layout Examples

SC-70 Board Layout (Actual size = 1.5 in \times 1.5 in

Figure 64. Layer 1 Silk

SC-70 Board Layout (Actual size = 1.5 in \times 1.5 in

Figure 65. Layer 2 Silk

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For additional information, see the following:

- Application Note 1013, *Video Amplifier Design for Computer Monitors*, [SNVA031](http://www.ti.com/lit/pdf/SNVA031)
- Application Note OA-15, *Frequent Faux Pas in Applying Wideband Current Feedback Amplifiers*, [SNOA367](http://www.ti.com/lit/pdf/SNOA367)

11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 5. Related Links

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

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11.4 Trademarks

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11.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

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PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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OTHER QUALIFIED VERSIONS OF LMH6601, LMH6601-Q1 :

_● Catalog: [LMH6601](http://focus.ti.com/docs/prod/folders/print/lmh6601.html)

• Automotive: [LMH6601-Q1](http://focus.ti.com/docs/prod/folders/print/lmh6601-q1.html)

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TEXAS NSTRUMENTS

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

PACKAGE MATERIALS INFORMATION

www.ti.com 30-Oct-2021

*All dimensions are nominal

PACKAGE OUTLINE

DCK0006A SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- 4. Falls within JEDEC MO-203 variation AB.

EXAMPLE BOARD LAYOUT

DCK0006A SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0006A SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.

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